

## Title (en)

Ceramic, graded resistivity monolith using the ceramic, and method of making

## Title (de)

Keramik, Monolith mit abgestuftem Widerstand mit der Keramik und Herstellungsverfahren

## Title (fr)

Monolithe en céramique à résistivité à gradient utilisant la céramique et procédé de fabrication

## Publication

**EP 2599760 A1 20130605 (EN)**

## Application

**EP 12194916 A 20121129**

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## Abstract (en)

According to one embodiment, a monolithic cassette (200) with graded electrical resistivity is presented. The monolithic cassette (200) has a continuous grain structure between a first end (202) (202) and a second end (204) (204); wherein electrical resistivity of the monolithic cassette (200) is graded such that the resistance varies continuously from the first end (202) to the second end (204). Methods and compositions for forming the monolithic cassette (200) are also presented.

## IPC 8 full level

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## Citation (search report)

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